

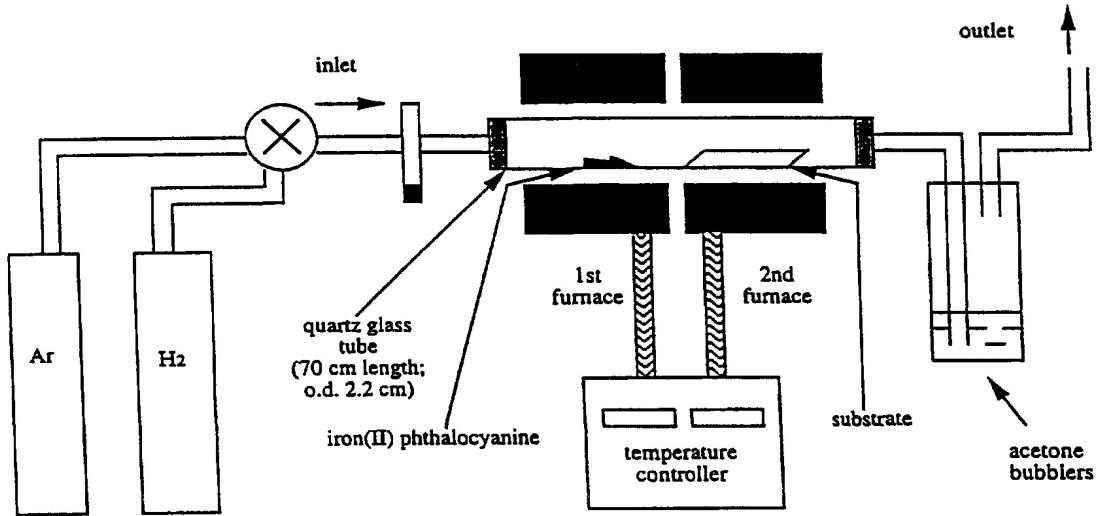


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(54) Title: MULTILAYER CARBON NANOTUBE FILMS



(57) Abstract

This invention relates to a process for the preparation of a substrate-free aligned nanotube film comprising: (a) synthesising a layer of aligned carbon nanotubes on a quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation; and (b) etching quartz glass substrate at the nanotube/substrate interface to release said layer of aligned nanotubes from the substrate. Another aspect of the invention provides a process for the preparation of multilayer carbon nanotube film comprising depositing a substrate-free carbon nanotube film onto another nanotube film. In yet another aspect of the invention there is provided a process for the preparation of a "hetero-structured" multilayer carbon nanotube film which includes one or more carbon nanotube layers together with layers of other materials, such as metal, semiconductor and polymer.

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Multilayer Carbon Nanotube Films

This invention relates to multilayer carbon nanotube materials with controllable layer thickness, diameter and packing density of the constituent nanotubes in each of the layers, and processes for their preparation. The invention also relates to hetero-structured multilayer 5 carbon nanotube materials including one or more layers of carbon nanotubes and to processes for their preparation. The invention also relates to the construction of devices from such materials for practical applications in many areas including as electron field emitters, artificial actuators, chemical sensors, gas storages, molecular-filtration membranes, energy-absorbing materials, molecular transistors and other optoelectronic devices.

10

Carbon nanotubes usually have a diameter in the order of tens of angstroms and the length of up to several micrometers. These elongated nanotubes consist of carbon hexagons arranged in a concentric manner with both ends of the tubes normally capped by pentagon-containing, fullerene-like structures. They can behave as a semiconductor or metal depending on their 15 diameter and helicity of the arrangement of graphitic rings in the walls, and dissimilar carbon nanotubes may be joined together allowing the formation of molecular wires with interesting electrical, magnetic, nonlinear optical, thermal and mechanical properties. These unusual properties have led to diverse potential applications for carbon nanotubes in material science and nanotechnology. Indeed, carbon nanotubes have been proposed as new materials for 20 electron field emitters in panel displays, single-molecular transistors, scanning probe microscope tips, gas and electrochemical energy storages, catalyst and proteins/DNA supports, molecular-filtration membranes, and energy-absorbing materials (see, for example: M. Dresselhaus, *et al.*, *Phys. World*, January, 33, 1998; P.M. Ajayan, and T.W. Ebbesen, *Rep. Prog. Phys.*, 60, 1027, 1997; R. Dagani, *C&E News*, January 11, 31, 1999).

25

For most of the above applications, it is highly desirable to prepare aligned carbon nanotubes so that the properties of individual nanotubes can be easily assessed and they can be incorporated effectively into devices. Carbon nanotubes synthesised by most of the common techniques, such as arc discharge and catalytic pyrolysis, often exist in a randomly entangled 30 state (see, for example: T.W. Ebbesen and P.M. Ajayan, *Nature* 358, 220, 1992; M. Endo *et al.*, *J. Phys. Chem. Solids*, 54, 1841, 1994; V. Ivanov *et al.*, *Chem. Phys. Lett.*, 223,

329, 1994). However, aligned carbon nanotubes have recently been prepared either by post-synthesis manipulation (see, for example: M. Endo, *et al.*, *J. Phys. Chem. Solids*, 54, 1841, 1994; V. Ivanov, *et al.*, *Chem. Phys. Lett.*, 223, 329, 1994; H. Takikawa, *et al.*, *Jpn. J. Appl. Phys.*, 37, L187, 1998) or by synthesis-induced alignment (see, for example: 5 W. Z. Li, *Science*, 274, 1701, 1996; Che, G., *Nature*, 393, 346, 1998; Z. G. Ren, *et al.*, *Science*, 282, 1105, 1998; C. N., Rao, *et al.*, *J.C.S., Chem. Commun.*, 1525, 1998).

Multilayer structures built up from aligned carbon nanotubes are of vital interest, as the use of multilayered semiconductor materials and devices has been demonstrated to be highly 10 desirable for many applications. Examples include the use of molecular-beam epitaxy for making superlattices consisting of the alternating layers of gallium arsenide and aluminium arsenide as hetero-structured semiconductor materials (M.A. Herman and H. Sitter, "*Beam Epitaxy: Fundamentals and Current Status*", Springer-Verlag, Berlin, 1989), the use of Langmuir-Blodgett and chemical vapor deposition techniques for construction of organic field- 15 emission transistors (M.F. Rubner and T.A. Skotheim, in "*Conjugated Polymers*", J. L. Brédas and R. Silbey (eds.), Kluwer Academic Publishers, Dordrecht, 1991; G. Horowitz, *Adv. Mater.*, 10, 365, 1998), and the use of layer-by-layer adsorption and solution-spinning methods for preparing multilayer thin films of conjugated polymers as organic light-emitting diodes (S.A. Jenekhe and K.J. Wynne, "*Photonic and Optoelectronic Polymers*", ACS Sym. 20 Ser. 672, ACS Washington, DC, 1995; L. Dai, *J. Macromole. Sci., Rev. Macromole. Chem. Phys.* 1999, 39(2), 273-387). The overall properties of multilayer materials and/or devices are highly dependent on not only the intrinsic properties characteristic of the constituent materials in each of the layers but also the particular layer stacking sequence, the interface and surface structures, thus adding additional parameters for the design and control 25 of their behaviours. It has now been found that multilayer structures of the perpendicularly-aligned carbon nanotubes over large areas can be prepared either by sequential syntheses or by transferring substrate-free nanotube films.

According to a first aspect, the present invention provides a process for the preparation of a 30 substrate-free aligned nanotube film comprising:

- 3 -

- (a) synthesising a layer of aligned carbon nanotubes on a quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation; and
- 5 (b) etching quartz glass substrate at the nanotube/substrate interface to release said layer of aligned nanotubes from the substrate.

Separating the layer of aligned nanotubes by etching the quartz glass substrate allows the resulting nanotube film to be deposited on another substrate, such as an electrode, and/or to
10 be included as a layer in a multilayer materials, with the integrity of the aligned nanotubes being largely maintained in the transferred films.

The carbon-containing material may be any compound or substance which includes carbon and which is capable for forming carbon nanotubes when subjected to pyrolysis in the
15 presence of a suitable catalyst. Examples of suitable carbon-containing materials include alkanes, alkenes, alkynes or aromatic hydrocarbons and their derivatives, for example methane, acetylene, benzene, transition metal phthalocyanines, such as Fe(II) phthalocyanine, and other organometallic compounds such as ferrocene and nickel dicyclopentadiene.

20 The catalyst may be any compound, element or substance suitable for catalysing the conversion of a carbon-containing material to aligned carbon nanotubes under pyrolytic conditions. The catalyst may be a transition metal, such as Fe, Co, Al, Ni, Mn, Pd, Cr or alloys thereof in any suitable oxidation state.

25 The catalyst may be incorporated into the substrate or may be included in the carbon-containing material. Examples of carbon-containing materials which include a transition metal catalyst are Fe(II) phthalocyanine, Ni(II) phthalocyanine, nickel dicyclopentadiene and ferrocene. When the catalyst and carbon-containing material are included in the same material it may be necessary to provide sources of additional catalyst or additional carbon-containing
30 material. For example, when ferrocene is used as the catalyst and a source of carbon, it is necessary to provide an additional carbon source, such as ethylene, to obtain the required

nanotube growth.

The pyrolysis condition employed will depend on the type of carbon-containing material employed and the type of catalyst, as well as the length and density of the nanotubes required.

5 In this regard it is possible to vary the pyrolysis conditions, such as the temperature, time, pressure or flow rate through the pyrolysis reactor, to obtain nanotubes having different characteristics.

For example, performing the pyrolysis at a higher temperature may produce nanotubes having
10 different base-end structures relative to those prepared at a lower temperature. The pyrolysis will generally be performed within a temperature range of 800°C to 1100°C. Similarly lowering the flow rate through a flow-type pyrolysis reactor may result in a smaller packing density of the nanotubes and vice versa. A person skilled in the art would be able to select and control the conditions of pyrolysis to obtain nanotubes having the desired characteristics.

15

The quartz glass substrate may be etched by subjecting the coated quartz glass substrate to any conditions capable of releasing the carbon nanotube film from the substrate or of dissolving the quartz glass substrate. For example the coated substrate may be immersed or otherwise contacted with an aqueous solution of hydrofluoric acid.

20

In another aspect of the present invention there is provided a process for the preparation of a multilayer carbon nanotube film comprising:

- (a) synthesising a layer of aligned carbon nanotubes on a suitable substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation to provide a nanotube coated substrate;
- (b) synthesising a further layer of aligned carbon nanotubes on said nanotube coated substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation.

- 5 -

According to this aspect the substrate may be any substrate capable of withstanding the pyrolysis conditions employed, and capable of supporting aligned carbon nanotube growth. Examples of suitable substrates include quartz glass, mesoporous silica, nanoporous alumina, ceramic plates, glass, graphite and mica. Preferably the substrate is quartz glass.

5

The second step of this aspect of the invention may be repeated to provide three or more layers of carbon nanotubes.

The pyrolysis conditions employed for step (b) may be the same or different to the conditions
10 employed for step (a). Similarly the pyrolysis conditions associated with the synthesis of any additional layers may be the same or different to the conditions employed in steps (a) and (b). Change of pyrolysis conditions may provide layers of differing structures which would lead to different characteristics e.g. conductivity, for each of the nanotube layers, enabling the manufacture of diode-like electronic devices or of asymmetric layered composite materials
15 with different materials on each surface.

It is also possible to prepare a substrate-free multilayer film of aligned carbon nanotubes by selecting quartz glass as the substrate and releasing the film from the substrate in accordance with the methodology described above.

20

In a further aspect of the present invention there is provided a process for the preparation of a multilayer carbon nanotube film comprising depositing a substrate-free carbon nanotube film onto another carbon nanotube film.

25 This aspect represents an alternative process for forming multilayer carbon nanotube films. According to this aspect of the invention a carbon-nanotube film, which may be mono or multilayered, is released from the quartz glass substrate on which it is formed and deposited as additional layer(s) on another carbon nanotube film, which itself may be mono or multilayered and which may be attached to a substrate or substrate-free. This process may
30 be repeated in order to increase the number of layers.

In yet another aspect of the present invention there is provided a process for the preparation of a substrate-free hetero-structured multilayer carbon nanotube film comprising:

- (a) synthesising a layer of aligned carbon nanotubes on a metal, metal oxide or 5 semiconductor-coated quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation; and
- (b) etching said substrate at the quartz/metal surface to release said hetero-structured multilayer film from the quartz glass.

10

The term "hetero-structured" as used herein refers to a multilayer structure which includes one or more carbon nanotube layers together with layers of other materials, such as metal, semiconductor, polymer etc.

15 The metal used to coat the quartz glass substrate may be any suitable metal which is capable of supporting carbon nanotube growth under the pyrolysis conditions employed. Examples of suitable metals include Au, Pt, Cu, Cr, Ni, Fe, Co and Pd . Examples of suitable metal oxides include indium tin oxide (ITO), Al₂O₃, TiO₂ and MgO. Examples of semiconductor materials include gallium arsenide, aluminium arsenide, aluminium sulphide and gallium 20 sulphide

Prior to etching the hetero-structured film from the quartz glass substrate it is possible to add one or more further layers to the film. These additional layers may be carbon nanotube layers added by further pyrolysis of a carbon-containing material in the presence of a suitable 25 catalyst, or may be added by deposition of a substrate-free mono or multilayer aligned carbon-nanotube film. The additional layers may also include layers of other materials, such as metal, metal oxide, semiconductor material or polymers, deposited onto the carbon nanotube layer by any suitable method. Examples of suitable polymers include conjugated (conducting) polymers, temperature/pressure responsive polymers, bioactive polymers and engineering 30 resins.

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In another aspect the invention provides a process for the preparation of hetero-structured multilayer carbon nanotube film comprising intercalating a substrate free aligned carbon nanotube film into a multilayer structure.

5 In this regard the multilayer structure may include layers of metal, metal oxide, semiconductor materials or polymers.

In yet another aspect of the present invention there is provided a process for the preparation of a hetero-structured multilayer carbon nanotube film comprising:

10

(a) synthesising a layer of aligned carbon nanotubes on a quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation to provide a nanotube coated substrate;

15

(b) coating a layer of a pyrolysis resistant material onto said nanotube coated substrate to provide a hetero-structured multilayered substrate;

(c) synthesising a further layer of aligned carbon nanotubes on said hetero-structured multilayered substrate by pyrolysis of a carbon-containing material in the presence of

20

a suitable catalyst for nanotube formation.

As with the previously described aspects of the invention additional layers of carbon nanotubes or other materials may be included, and the film may be etched from the quartz glass substrate to provide a substrate-free film.

25

The multilayered film prepared in accordance with any one of the processes of the present invention and devices, materials coated with or including these multilayer films represent further aspects of the present invention.

30

As is evident from the above description the invention allows the preparation of a large variety of multilayer films and structures. It is also possible to provide patterned layers using appropriate masking and etching techniques. The processes of the present invention and the

film structures formed may have use in the following applications:

- 1) electron emitters
- 2) field-emission transistors
- 5 3) electrodes for photovoltaic cells and light emitting diodes
- 4) optoelectronic elements
- 5) bismuth actuators
- 7) chemical and biological sensors
- 8) gas storages
- 10 9) molecular-filtration membranes
- 10) energy absorbing materials.

The invention can be more fully understood from the following detailed description of several examples, in which reference is made to the accompanying drawings. It should be understood 15 that the examples described are only for an illustration purpose, which does not intend to constitute a limitation of the invention.

Referring to the drawings:

20 Figure 1 is a diagrammatic representation of a pyrolysis flow reactor suitable for preparing aligned carbon nanotubes according to the invention .

Figure 2a is a scanning electron microscopic image of aligned carbon nanotubes prepared in accordance with the present invention.

25 Figure 2b is a high resolution transmission electron microscopic image of an individual carbon nanotube.

Figure 3 is a scanning electron microscopic image of a double layer carbon nanotube structure 30 prepared by deposition of a substrate-free carbon nanotube film.

Figure 4a is a scanning electron microscopic image of a double layer carbon nanotube structure prepared using a first nanotube layer as a substrate for growth of a second layer.

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Figure 4b is similar to Figure 4a, except a reduced flow rate was employed during synthesis of the second layer.

Example 1

5 *Preparation of aligned carbon nanotubes*

Aligned carbon nanotubes were prepared by pyrolysis of iron (II) phthalocyanine under Ar/H₂ at 800-1100°C using an appropriate substrate in a flow reactor consisting of a quartz glass tube and a dual furnace fitted with independent temperature controllers (Figure 1). Figure 2a represents a typical scanning electron microscopic (SEM, XL-30 FEG SEM, Philips, at 5 KV) 10 image of the carbon nanotubes, showing that the *as-synthesised* nanotubes align almost normal to the substrate surface. The aligned nanotubes are densely packed with a fairly uniform tubular length of *ca.* 25 µm. However, the length of the aligned nanotubes can be varied over a wide range (from a few to several tens of micrometers) in a controllable fashion by changing the experimental conditions (e.g. the pyrolysis time, flow rate). A well-graphitised 15 structure with *ca.* 40 concentric carbon shells and an outer diameter of *ca.* 40 nm is illustrated in the high resolution transmission electron microscopic (HR-TEM, CM30, Philips, at 300 KV) image of an individual nanotube (Figure 2b).

Example 2

20 *Preparation of substrate-free films of the aligned carbon nanotubes*

The carbon nanotubes prepared in Example 1 appear on the substrate (e.g. a quartz glass plate) as a black layer, which could be scraped off from the substrate as powder. More importantly, the black deposit was easily separated from the quartz glass as a substrate-free, floating film simply by immersing the nanotube-deposited quartz plate into an aqueous 25 hydrofluoric acid solution (10-40% w/w). This technique allows a transfer of the nanotube films onto various other substrates of particular interest (e.g. electrodes for electrochemistry) with the integrity of the aligned nanotubes largely maintained in the transferred films.

Example 3

30 *Preparation of multilayer nanotube films by repetitively transferring the freely-suspended films*

The substrate-free films of the aligned nanotubes can be readily transferred onto various

- 10 -

substrates including those which otherwise may be not be suitable for nanotube growth at high temperatures (e.g. polymer films) by the Langmuir-Blodgett technique. By repetitively depositing the substrate-free nanotube films on each other, multilayer films of the aligned carbon nanotubes (as shown in Figure 3 for a double layer structure) can be obtained. It is
5 noted that hetero-structured multilayer films with foreign components intercalated between any two consecutive layers can be made by alternatively depositing the substrate-free nanotube film and the foreign material.

Example 4

10 *Multilayer nanotube films were prepared by an in-situ growth process during the pyrolysis*
Figure 4a shows a typical scanning electron microscopic image of a double layer carbon nanotube films prepared by using the first nanotube layer as the substrate or the growth of the second layer nanotubes in a separate experiment. Figure 4b shows a corresponding SEM
image of a double layer nanotube film produced by reducing the monomer flow rate upon the
15 formation of the first nanotube layer, showing a smaller packing density for the second nanotube layer. As can be seen, therefore, the length and packing density of the aligned nanotubes in each of the layers can be varied by choosing different synthetic routes and/or changing the experimental conditions (e.g. the pyrolysis time, flow rate). Furthermore, the synthetic process associated with Figure 4a should allow hetero-structured multilayer
20 nanotube films to be made by introducing foreign materials (e.g. Au, Pt, Cu and ITO)
between any of the two consecutive layers.

Throughout this specification and the claims which follow, unless the context requires otherwise, the word "comprise", and variations such as "comprises" and "comprising", will be
25 understood to imply the inclusion of a stated integer or step or group of integers or steps but not the exclusion of any other integer or step or group of integers or steps.

Those skilled in the art will appreciate that the invention described herein is susceptible to variations and modifications other than those specifically described. It is to be understood
30 that the invention includes all such variations and modifications. The invention also includes all of the steps, features, compositions and compounds referred to or indicated in this specification, individually or collectively, and any and all combinations of any two or more of said steps or features.

CLAIMS:

1. A process for the preparation of a substrate-free aligned nanotube film comprising:
 - 5 (a) synthesising a layer of aligned carbon nanotubes on a quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation; and
 - (b) etching quartz glass substrate at the nanotube/substrate interface to release said layer of aligned nanotubes from the substrate.
- 10 2. A process according to claim 1, wherein the carbon-containing material is selected from alkanes, alkenes, alkynes, aromatic hydrocarbons and their transition metal derivatives.
- 15 3. A process according to claim 1 wherein the catalyst includes a transition metal.
4. A process according to claim 3 wherein the catalyst is selected from Fe, Co, Al, Ni, Mn, Pd, Cr and alloys thereof in any suitable oxidation state.
- 20 5. A process according to claim 1 wherein the catalyst is incorporated into the substrate.
6. A process according to claim 1 wherein at least a portion of the catalyst is included in the carbon-containing material.
- 25 7. A process according to claim 6 wherein the carbon containing material which includes a catalyst is selected from Fe(II) phthalocyanine, Ni(II) phthalocyanine, ferrocene and nickel dicyclopentadiene.
8. A process according to claim 6 wherein sources of additional catalyst or additional 30 carbon-containing material are provided in the pyrolysis step.

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9. A process according to claim 1 wherein pyrolysis is performed within a temperature range of 800°C to 1100°C.

10. A process according to claim 1 wherein step (a) is conducted in a flow-type pyrolysis
5 reactor.

11. A process according to claim 10 wherein the aligned carbon molecules synthesised in the substrate have a packing density which is controlled by adjusting the flow rate of carbon-containing material through the reactor.

10

12. A process according to claim 1 wherein the layer of aligned molecules is etched from the substrate by immersing or otherwise contacting the coated substrate with an aqueous solution of hydrofluoric acid.

15 13. A process for the preparation of a multilayer carbon nanotube film comprising:

(a) synthesising a layer of aligned carbon nanotubes on a suitable substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation to provide a nanotube coated substrate;

20

(b) synthesising a further layer of aligned carbon nanotubes on said nanotube coated substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation.

25 14. A process according to claim 13 wherein the substrate is selected from quartz glass, mesoporous silica, nanoporous alumina, ceramic plates, glass, graphite and mica.

15. A process according to claim 14 wherein the substrate is quartz glass.

30 16. A process according to claim 13 wherein step (b) is repeated to provide three or more layers of carbon nanotubes.

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17. A process according to claim 13 wherein the further layer is synthesised employing conditions which are different to those employed in step (a).

18. A process for the preparation of a substrate-free hetero-structured multilayer carbon 5 nanotube film comprising:

(a) synthesising a layer of aligned carbon nanotubes on a metal, metal oxide or semiconductor-coated quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation; and

10

(b) etching said substrate at the quartz/metal surface to release said hetero-structured multilayer film from the quartz glass.

19. A process according to claim 18 wherein the quartz glass substrate is coated with a 15 metal selected from Au, Pt, Cu, Cr, Ni, Fe, Co and Pd, a metal oxide selected from indium tin oxide (ITO), Al_2O_3 , TiO_2 and MgO or a semiconductor material selected from gallium arsenide, aluminium arsenide, aluminium sulphide and gallium sulphide.

20. A process for the preparation of hetero-structured multilayer carbon nanotube film 20 comprising intercalating a substrate free aligned carbon nanotube film into a multilayer structure.

21. A process for the preparation of a hetero-structured multilayer carbon nanotube film comprising:

25

(a) synthesising a layer of aligned carbon nanotubes on a quartz glass substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation to provide a nanotube coated substrate;

30 (b) coating a layer of a pyrolysis resistant material onto said nanotube coated substrate to provide a hetero-structured multilayered substrate;

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- (c) synthesising a further layer of aligned carbon nanotubes on said hetero-structured multilayered substrate by pyrolysis of a carbon-containing material in the presence of a suitable catalyst for nanotube formation.

5 22. A substrate-free aligned carbon nanotube film prepared according to the process of claim 1.

23. A multilayer carbon nanotube further prepared according to the process of claim 13.

10 24. A substrate-free hetero-structured carbon nanotube further prepared according to the process of any one of claims 18, 20 or 21.

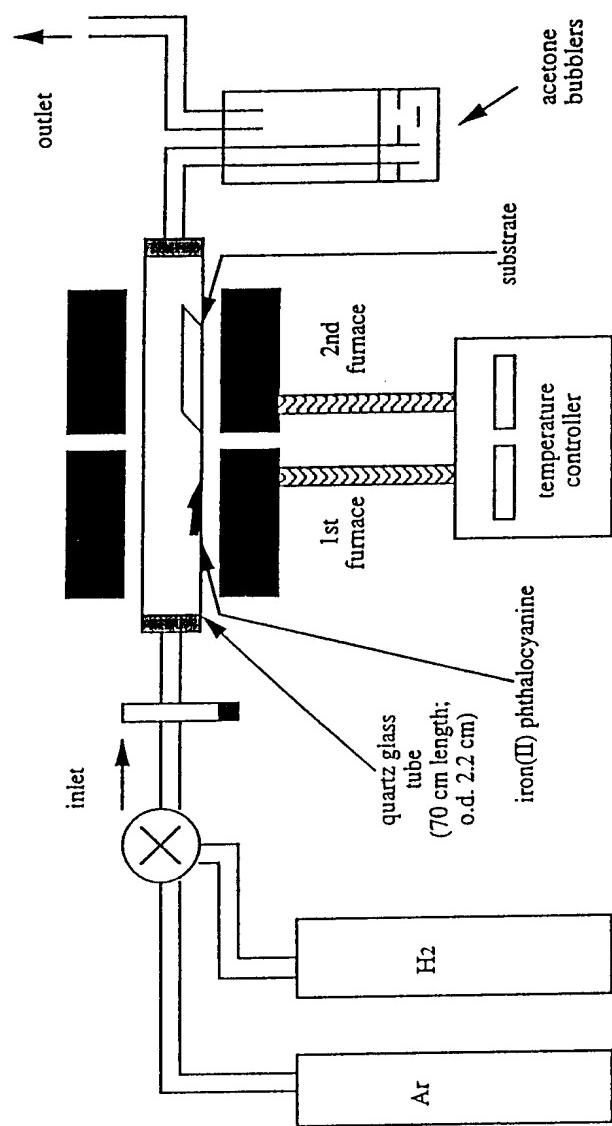


Figure 1

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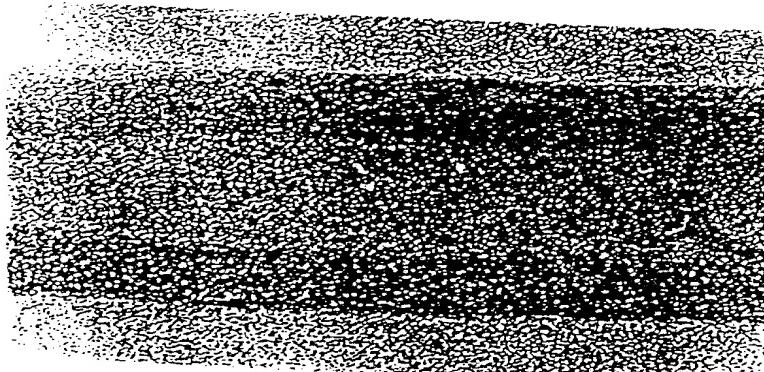


Figure 2b

(b)



Figure 2a

(a)

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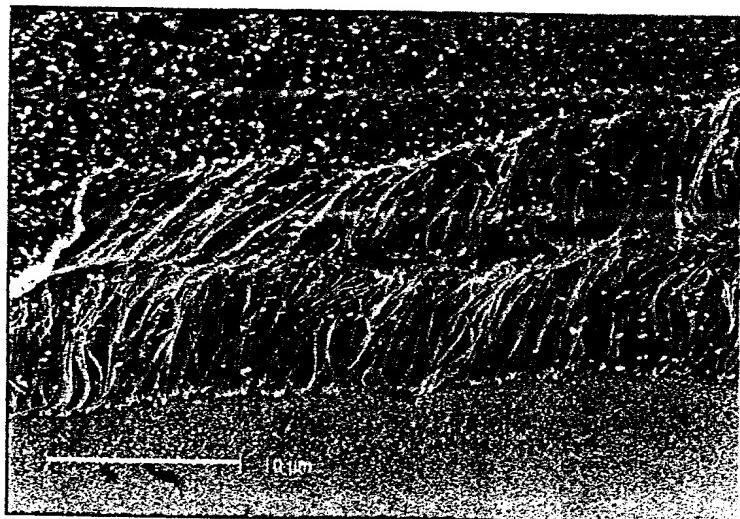


Figure 3

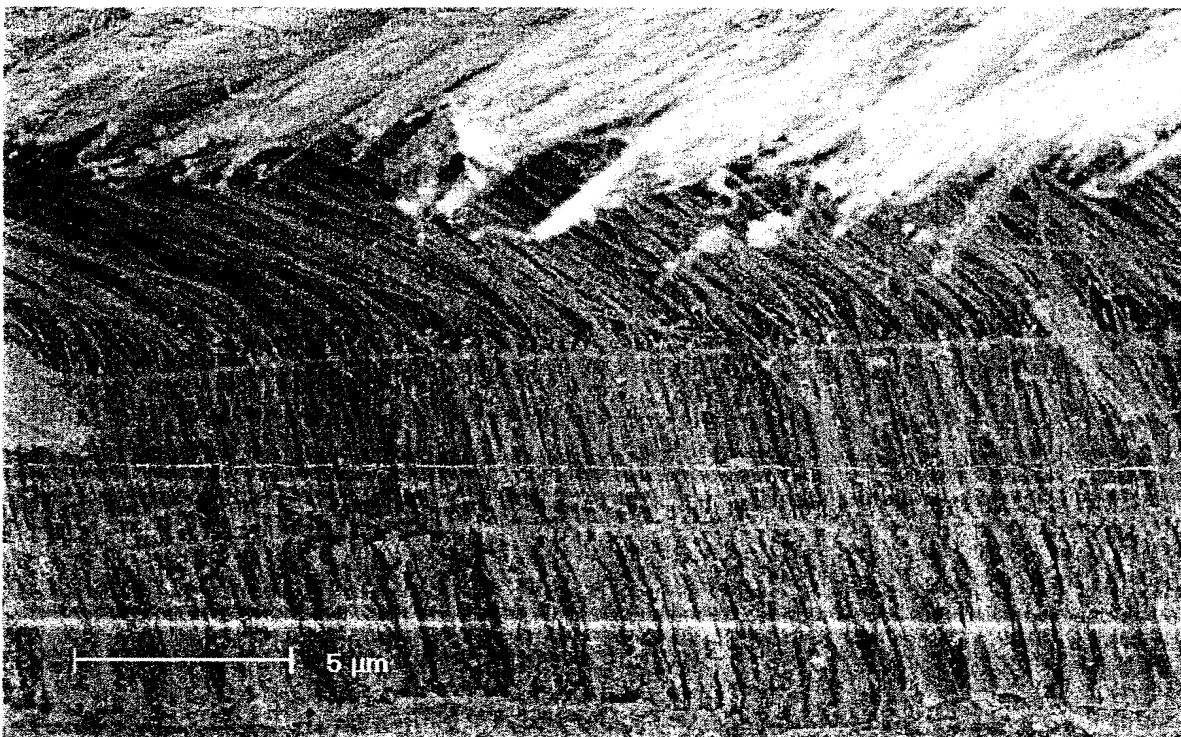


Figure 4a



Figure 4b

INTERNATIONAL SEARCH REPORT

International application No.
PCT/AU00/00324

A. CLASSIFICATION OF SUBJECT MATTER		
Int. Cl. ⁷ : C01B 31/02, D01F 9/12, 9/127		
According to International Patent Classification (IPC) or to both national classification and IPC		
B. FIELDS SEARCHED		
Minimum documentation searched (classification system followed by classification symbols) IPC: as above		
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched AU: IPC as above		
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) WPAT, JAPIO and STN (Search terms: carbon nanotube and film)		
C. DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	WO 99/65821A (THE RESEARCH FOUNDATION OF STATE UNIVERSITY OF NEW YORK) 23 December 1999 See whole document	1-24
A	EP 0947466A (JAPAN FINE CERAMICS CENTER) 6 October 1999 See whole document	1-24
A	Chemical Physics Letters 316 (2000) 349-355, 21 January 2000, Structure and Growth of Aligned Carbon Nanotube Films by Pyrolysis, D-C Li.	1-24
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Date of the actual completion of the international search 8 May 2000	Date of mailing of the international search report 12 MAY 2000	
Name and mailing address of the ISA/AU AUSTRALIAN PATENT OFFICE PO BOX 200, WODEN ACT 2606, AUSTRALIA E-mail address: pct@ipaaustralia.gov.au Facsimile No. (02) 6285 3929	Authorized officer ALBERT S. J. YONG Telephone No : (02) 6283 2160	

INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No.
PCT/AU00/00324

This Annex lists the known "A" publication level patent family members relating to the patent documents cited in the above-mentioned international search report. The Australian Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

Patent Document Cited in Search Report				Patent Family Member	
WO	99/65821	US	5996127		
EP	947466	JP	10265208	WO	9842620

END OF ANNEX